Zener Diode

DZ2706800L

Panasonic

DZ2706800L

Silicon epitaxial planar type

For constant voltage / For surge absorption circuit DZ2S068 in SSSMini2 type package

■ Features

- · Excellent rising characteristics of zener current Iz
- · Low zener operating resistance Rz
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol: GJ

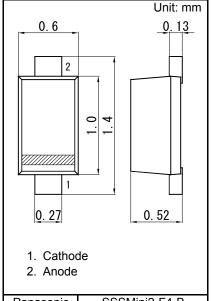
■ Packaging

Embossed type (Thermo-compression sealing): 10 000 pcs / reel (standard)

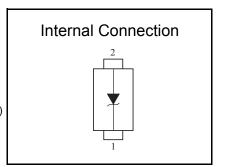
■ Absolute Maximum Ratings Ta = 25 °C

<u> </u>			
Parameter	Symbol	Rating	Unit
Repetitive peak forward current	IFRM	200	mA
Total power dissipation *1	PT	120	mW
Electrostatic discharge *2	ESD	±15	kV
Junction temperature	Tj	150	°C
Operating ambient temperature	Topr	-40 to +85	°C
Storage temperature	Tstg	-55 to +150	°C

Note)*1: Mounted on glass epoxy print board. (45 mm x 45 mm x 1 mm) Solder in (0.4 mm x 0.3 mm)



Panasonic	SSSMini2-F4-B
JEITA	SC-104A
Codo	SUD 733



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■ Electrical Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	VF	IF = 10 mA			1.0	V
Zener voltage *1, *2	VZ	IZ = 5 mA	6.46		7.14	V
Zener operating resistance	RZ	IZ = 5 mA			20	Ω
Zener rise operating resistance	RZK	IZ = 0.5 mA			60	Ω
Reverse current	IR	VR = 4.0 V			0.1	μA
Temperature coefficient of zener voltage *3	SZ	IZ = 5 mA		3.2		mV/°C

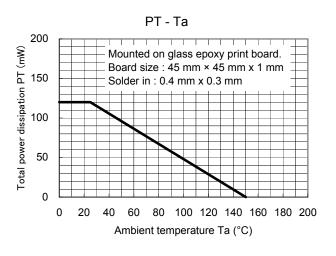
- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.
 - 2. Absolute frequency of input and output is 5 MHz.
 - *1 The temperature must be controlled 25°C for VZ mesurement.
 VZ value measured at other temperature must be adjusted to VZ (25°C)
 - *2 VZ guaranted 20 ms after current flow.
 - *3 Tj = 25°C to 150°C

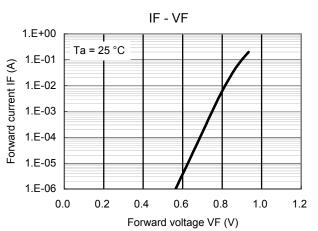
^{*2:} Test method:IEC61000_4_2(C = 150 pF,R = 330 Ω , Contact discharge:10 times)

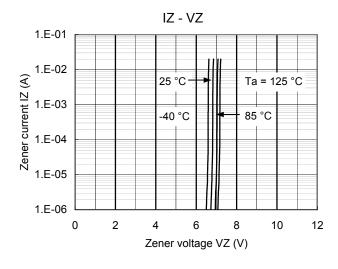
Zener Diode

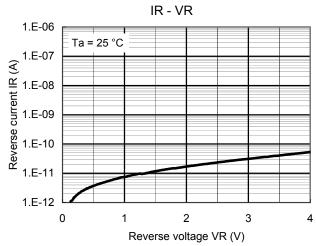
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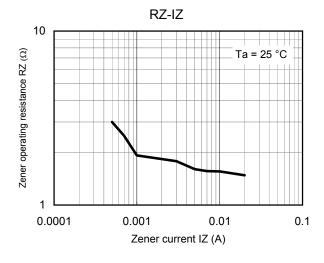
Technical Data (reference)

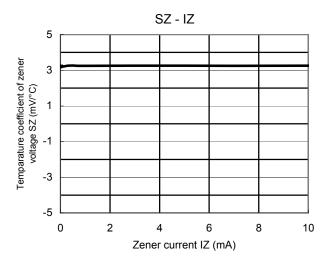








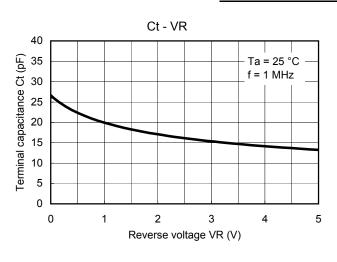


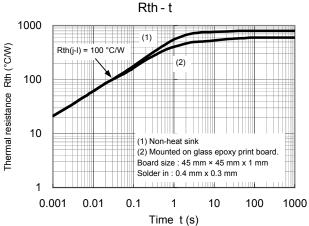


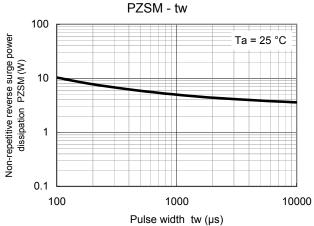
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Technical Data (reference)







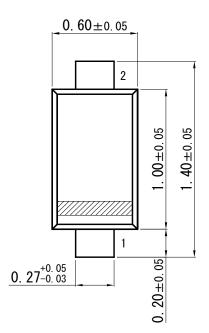
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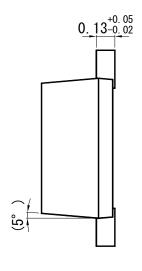
Zener Diode

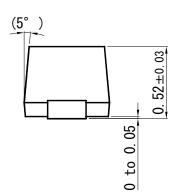
DZ2706800L

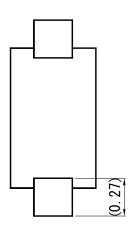
SSSMini2-F4-B

Unit: mm

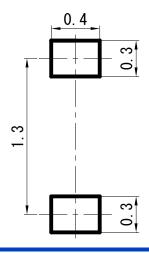








■ Land Pattern (Reference) (Unit: mm)



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